

## N-Channel Enhancement Mode Power MOSFET

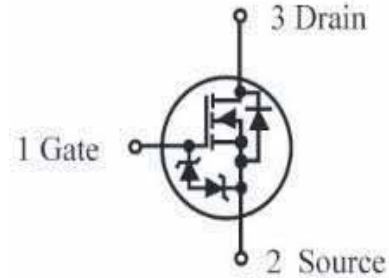
### General Features

- $V_{DS} = 60V, I_D = 0.34A$   
 $R_{DS(ON)} < 5.3\Omega @ V_{GS}=4.5V, I_D = 200 \text{ mA}$   
 $R_{DS(ON)} < 5.0\Omega @ V_{GS}=10V, I_D = 500\text{mA}$
- ESD Rating: HBM 1000V

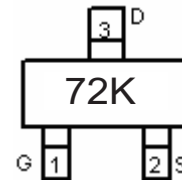
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

### Application

- Direct logic-level interface: TTL/CMOS
- Drivers: relays, solenoids, lamps, hammers, display, memories, transistors, etc.
- Battery operated systems
- Solid-state relays
- Halogen-free



Schematic diagram



Marking and pin assignment



SOT-23 top view

### Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
72K	2N7002KB	SOT-23	Ø180mm	8 mm	3000 units

### Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	0.34	A
Maximum Power Dissipation	$P_D$	0.35	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	$^\circ\text{C}$

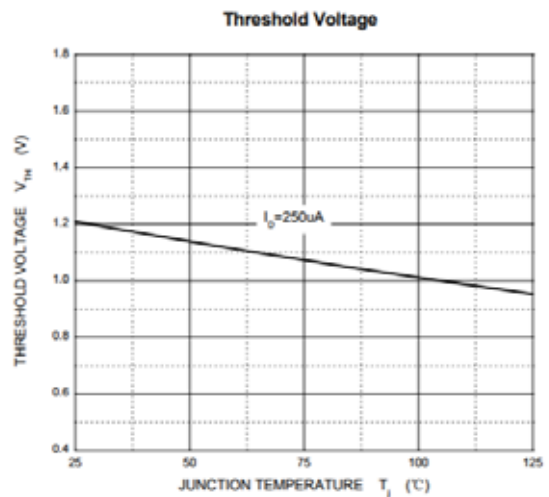
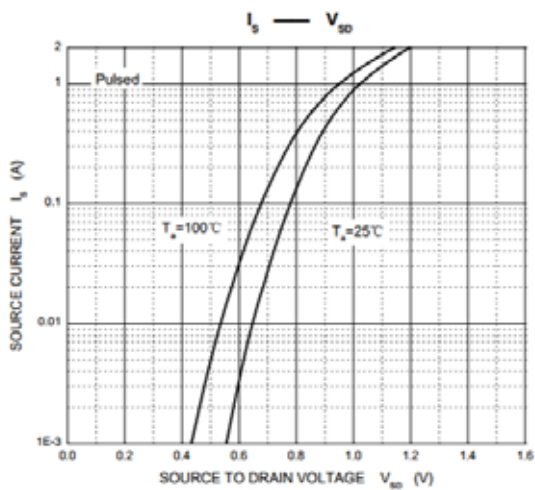
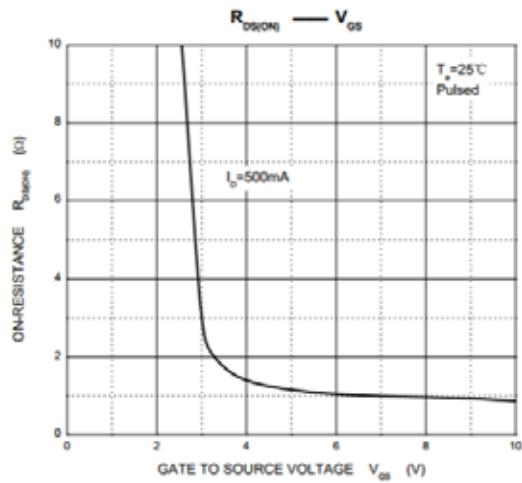
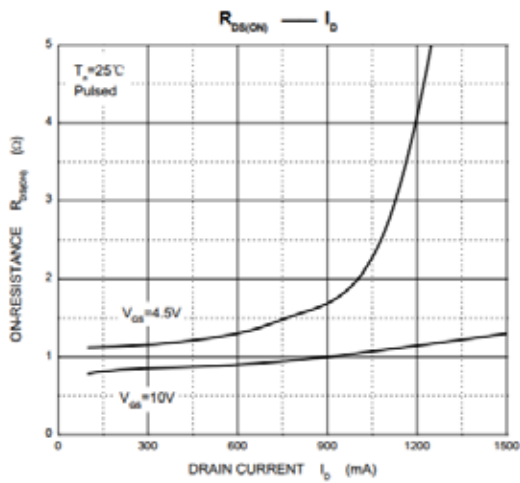
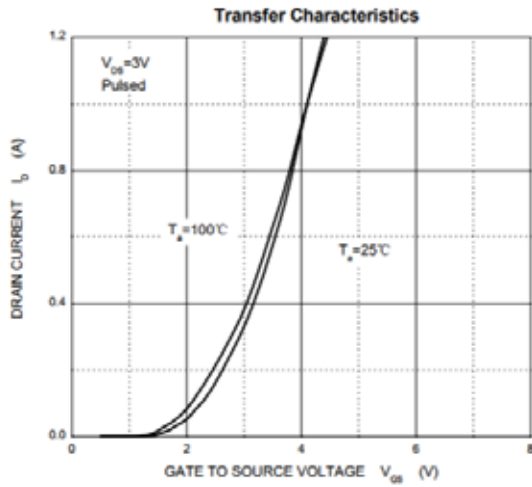
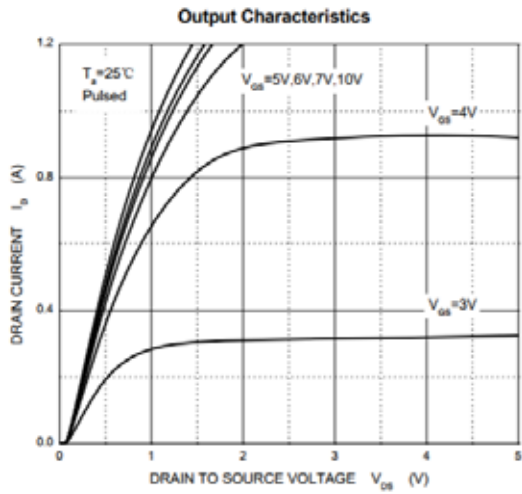
## Electrical Characteristics ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	60	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Body Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 1.0$	$\mu A$
<b>On Characteristics</b> <sup>(Note 3)</sup>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	-	2.5	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS}=4.5V, I_D=0.2A$	-	-	5.3	$\Omega$
		$V_{GS}=10V, I_D=0.5A$	-	-	5.0	$\Omega$
Forward Transconductance	$g_{FS}$	$V_{DS}\geq 2.0V, I_D=0.2A$	80	-	-	mS
<b>Dynamic Characteristics</b> <sup>(Note 4)</sup>						
Input Capacitance	$C_{iss}$	$V_{DS}=10V, V_{GS}=0V,$ $F=1.0MHz$	-	-	40	PF
Output Capacitance	$C_{oss}$		-	-	30	PF
Reverse Transfer Capacitance	$C_{rss}$		-	-	10	PF
<b>Switching Characteristics</b> <sup>(Note 4)</sup>						
Turn-on Delay Time	$t_{d(on)}$	$V_{DD}=50V, I_D=0.5A$ $V_{GS}=10V, R_{GEN}=50\Omega$	-	-	10	nS
Turn-Off Delay Time	$t_{d(off)}$		-	-	15	nS
Reverse recovery time	$t_{rr}$	$V_{GS}=0V, I_S=0.3A$ $V_R=25V, di/dt=-100A/us$	-	30	-	nS
Total Gate Charge	$Q_g$		-	30	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage <sup>(Note 3)</sup>	$V_{SD}$	$V_{GS}=0V, I_S=0.3A$	-	-	1.5	V
Diode Forward Current <sup>(Note 2)</sup>	$I_S$		-	-	0.3	A

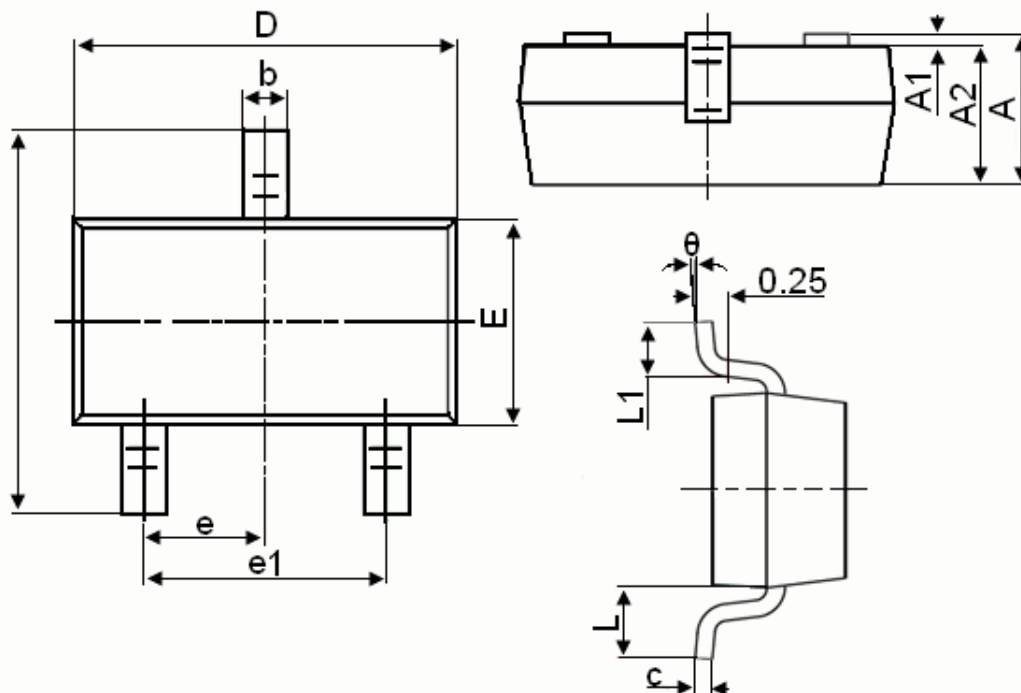
### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production

# RATING AND CHARACTERISTICS CURVES (2N7002KB)



## SOT-23 Package Information



Symbol	Dimensions in Millimeters	
	MIN.	MAX.
A	0.900	1.150
A1	0.000	0.100
A2	0.900	1.050
b	0.300	0.500
c	0.080	0.150
D	2.800	3.000
E	1.200	1.400
E1	2.250	2.550
e	0.950TYP	
e1	1.800	2.000
L	0.550REF	
L1	0.300	0.500
θ	0°	8°

### Notes

1. All dimensions are in millimeters.
2. Tolerance  $\pm 0.10\text{mm}$  (4 mil) unless otherwise specified
3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
4. Dimension L is measured in gauge plane.
5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.

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